

Advances in Data Center Power Supplies

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Introduction

Cisco Power Presentation

- Customer Power Requirements and Facility Power Distribution
- Efficiency and Power Savings with Facility Power Distribution
- FEP (Front-End-Power) Supplies Road Map
 - Digital power revolution in Power
- BMP (Board-Mounted-Power) Supplies

Cisco Power Culture and Goals

Provide World Class Power Systems to Meet Customer Needs

- **1. Reliability:** Provide best-in-class quality and reliability for system integrity with single-piont-of-failure tolerance
- 2. Efficiency: Energy saving and meet Green Energy Initiatives
- **3. Cost:** Lowest cost of ownership and ROI
- **4. Size:** Save space in systems and boards for important features in data performance
- 5. Technology: Leadership in advanced technology balanced with mature designs
- 6. Leadership: Work with meeting customers requirements and with supplier partners

Facility Power and System Power Efficiency

Data Systems Meet Power Savings and Green Power Needs

- Efficiency and power cost-of-ownership dictate facility voltages
- Power density limit power versus data rate system floor space
- Front-End-Power (FEP) supplies advanced technologies
 - Cost lowers with fewer supplies needed for N+1 & N+N redundancy with multiply input lines
 - Multiple input voltages and distributed power distribution voltages, i.e. 48VDC and 12VDC typical
 - Digital control with DSP/DSCs
 - Standardization with 1RU supply height and multi-use designs
- Board-Mounted-Power (BMP) supplies with advanced technologies
 - Intermediate-Bus-Converter (IBC) supplies and Point-Of-Load (POL) supplies
 - Power-Block POLs and digital control systems
 - 48:1V POL converters without IBC

Customer Facility Power Distribution Voltages and FEP Supply Input Voltages

Contemporary Power Distribution Efficiencies



HP Power Supply Efficiency Curves



Marcoux and Sumrell, 7x24 Exchange, "277V Power Supplies"

("Efficiency Gains with 480/277V Power at the Cabinet Level" paper by Server Technology)

Customer Facility Power Distribution Voltages and FEP Supply Input Voltages

Comparison						
Circuit Capacity	De-rated Value	208 VAC 3-Phase	415 VAC 3-Phase	480 VAC 3-Phase		
20 A	16 A	5.8 kW	11.5 kW	13.3 kW		
30 A	24 A	8.6 kW	17.3 kW	19.9 kW		
50 A	40 A	14.4 kW	28.8 kW	33.2 kW		
60 A	48 A	17.3 kW	34.6 kW	39.9 kW		
415 VAC 3-phase delivers twice the power of a 208 VAC 3-phase system, while 480VAC delivers 2.3 times						
• 208 VAC: 208V (phase to phase) x 24A x 1 732 = 8 646 W						

- 415 VAC: 240V (phase to neutral) x 24A x 3.0 = 17,280 W
- 480 VAC: 277V (phase to neutral) x 24A x 3.0 = 19,944 W

("Efficiency Gains with 480/277V Power at the Cabinet Level" paper by Server Technology)

Customer Facility Power Distribution Voltages and FEP Supply Input Voltages



("The Transition Path to DC" paper by dcFUSION, Ilc)

Customer Facility Power Distribution Voltages and FEP Supply Input Voltages

End to End Efficiency

					IT Power		Overall
Power	UPS		Distribution		Supply		Efficiency
480/277 VAC	96.20	X	99.50	X	92.00 =	=	88.10%
400/230 VAC	96.20	X	99.50	Х	90.25 =	=	86.39%
480 to 208VAC	96.20	X	96.52	Х	90.00 =	=	85.00%
48V DC	92.86	Х	99.50	Х	91.54 =	=	84.58%
380V DC	96.00	X	99.50	Х	91.75 =	-	87.64%
Hybrid 575V DC	95.32	Х	92.54	Х	91.54 =	=	80.75%

("Efficiency Gains with 480/277V Power at the Cabinet Level" paper by Server Technology)

Efficiency Improvement Value Example

The following chart shows the importance of every percent of efficiency improvement as we get closer to 100% efficiency

Efficiency	1	eff Saving	Improvement Net
Efficiency	Losses	Improvement	Effect
80%	20%	1%	5.00%
81%	19%	1%	5.26%
82%	18%	1%	5.56%
83%	17%	1%	5.88%
84%	16%	1%	6.25%
85%	15%	1%	6.67%
86%	14%	1%	7.14%
87%	13%	1%	7.69%
88%	12%	1%	8.33%
89%	11%	1%	9.09%
90%	10%	1%	10.00%
91%	9%	1%	11.11%
92%	8%	1%	12.50%
93%	7%	1%	14.29%
94%	6%	1%	16.67%
95%	5%	1%	20.00%
96%	4%	1%	25.00%
97%	3%	1%	33.33%
98%	2%	1%	50.00%
99%	1%	1%	100.00%
100%	0%		

FEP Supply Input Power Requirements

World-Wide Input Voltage Requirements to Support

- -48/60VDC Telco input models (40-75VDC)
- 120VAC input models (85-132VAC)
- 120/240VAC input models (85-264VAC)
- 240VAC input models (170-264VAC)
- 277VAC input models (200-305VAC)
- 240VDC (China Narrow Range) (220-240VDC)
- 240VDC (China HVDC Standard) (192-288VDC)
- 260-400VDC (Emerge Standard) wide range
- 380VDC (Emerge Standard) narrow range (360-400VDC)
- 120/240/277VAC and HVDC 192-400VDC universal input

- Cisco HVAC, HVDC, & HVAC/HVDC FEP Supplies as of March 2016 are in development and production with 80 PLUS Gold, Platinum, and Titanium, 12V and 54VDC outputs, 500W to 3500W power output in 1RU high form factors.
- Samples of Cisco HVAC/HVDC FEP Supplies (March 2015)



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FEP Supply Efficiency Road Map

- Topology advances
 - Interleaved power circuits, Resonant switching (HB-LLC and quasi-resonant PS-FB), Totem pole or Bridgeless PFC.
- Controller advances

Platinum &

Titanium

- Advanced PWM control ICs, Adaptive Digital control to maximize efficiency at different Line/Load conditions, Variable switching frequency, pulse skipping, phase dropping etc. for improved light load efficiency.
- Component technology advance

92%-96% peak efficiency Platinum, Platinum+ (flat),

- High Voltage Schottky, SiC, GaN, Sync FETs. Thermal efficient packaging.
- Planar Magnetics, Bus-Bar conductors, integrated assemblies.
- New magnetic materials, new geometries, integrated magnetics.
- Low loss Aux power and low loss fans.

Platinum & Titanium



96% + peak efficiency Titanium and Titanium+ (flat)



94%-96% peak efficiency

Platinum+ and Titanium

ra cin c

Titanium



FEP High Power Density Road Map

- 97%+ efficiency with advanced topology, Controller Scheme and new Semi.
- Packaging and assembly improvements.
 - Thermal efficient packaging for Semi and power supply.
 - Planar Magnetics with hi Bsat materials.
 - Modular designs with BMP assemble tech used in the module.
 - Bus-Bar conductors, new geometries magnetics
- New circuit between PFC and DCDC to minimize the Bulk capacitance.
- Real time monitor and reporting to minimize design margin for components.
- Battery Backup in system to reduce the Holdup requirement.
- GaN to boost Switching frequency and reduce size.
- HVAC/HVDC

• 55-60W/in³ power density

• 65W+/in³ power density for routing and 70W+/in³ for Server

• 42-45W/in³ power density



Digital Smart Front-End Power (FEP) Supplies

- Digital control has replaced analog control in recent years
- Digital Signal Processor (DSP) and Digital Signal Controller (DSC)
 CPUs make the FEP supplies smarter subsystems of the system platforms
- DSPs in the last 5-6 years have taken over most control functions of the FEP
- System demands for smart control, data, and features from the power supply are increasingly more complex
- FW design is now a major part with the HW design

DSP Advantages for FEP Supplies

- Replacement of many discrete analog and digital circuits and components
- Reduces board space for higher power density, lowers costs, improves reliability, and improves efficiency
- Provides added functionality and features including advanced power topology control techniques and more smart control
- Allows fast cut-n-try problem solving
- Higher efficiency optimization with adaptive control from input, output, and temperature dynamic variables and tighten tolerances and lower drift
- Transient response improved with hysteretic or predictive and adaptive control technique options

DSP Advantages for FEP Supplies

- Eliminates I²C communication chip sets that are included in the DSPs
- **Reliability** with self-test, self calibration, and prognosis
- **EMI reduction** by noise cancellation & frequency dithering ability
- Reusable FW code to simplify and speed development of new designs
- Easy design changes with FW and to mitigate HW changes to upgrade supplies without PCB re-spins
- Allowing field FW upgrades with boot-loader through system or Internet to avoid returning supplies

DSP Disadvantages for FEP Supplies

- Disadvantages include schematic review and traditional circuit analysis tools no longer available to understand the design
- Need special attention with design review, logic diagrams, and testing of control functions, modes, levels, timing, and decisions of power supply responses under dynamic line, load, and temperature conditions
- Black-Box analysis needed but limited with traditional design review and design validation testing (DVT)
- More smart systems interface and communications problems between the FEP supplies and the system than power problems

Typical FEP Analog/Digital Design 5-10 Years Ago

Typical Analog based AC/DC rectifier



Typical DSP Primary-Side Design Today with DSP

Digital control example shown with 1 DSP, but most FEP supplies use 2 or more DSPs.

Digital approach with Single Device example for AC/DC Rectifier



Technology for Innovators

U Texas Instruments

Power Factor Correction (PFC) Circuit Design

PFC Rectifier Stage Topology with High Efficiency Example



Typical Bridge Rectifier PFC stage with PWM Controller (STMicroelectronics AN1606 Application Note)



Bridgeless Rectifier PFC stage with PWM Controller (STMicroelectronics AN1606 Application Note)

Series/Parallel Resonant (LLC) Converter Design LLC DC/DC Converter (typical for high efficiency)



Figure 2.1 Full-Bridge LLC converter with Full-Bridge rectifier

(From Infineon Application Note AN 2012-09)

Board Mount Power

- Present state of BMP technology
- What next?
- Advanced semiconductors
- Other components

Now:

On-Board Power Regulators

CPU Power, On-Board & Discrete

- 12 V Input, non-isolated
 - To 320 A output current
 - 4 Φ to 8 Φ

Power Modules

- 12 V Input, non-isolated
 - 25 A to 130 A output current
 - High Power Density (> 200 A/in², > 450 A/in³)
 - High cost

On-Board, discrete

- 12 V Input, non-isolated, single / dual phase
 - 4 A to 80 A output current
 - High Power Density (to > 80 A/in²)
 - Low cost

Next Generation:

On-Board Power Regulators

48 V Input, non-isolated

- Lower distribution losses
- Enables higher power systems

Power Modules

- 48 V Input, isolated
 - Higher output power (> 1200W, ¼ Brick)
 - Higher output current

On-Board, discrete

- 48 V Input, non-isolated, single / dual phase
 - Higher output current
 - Smaller, increased Power Density

Advanced Semiconductors

GaN

- Typically 600 V 800 V, some Low V
- High Switching Speed
 - Low Capacitances / Gate Charge
- No D-S parasitic Diode
- No Avalanche mode
- High Temperature
- Basic structure: Normally On
- Moderate Cost (GaN on Si)

SiC

- Typically 600 V 1200 V
- Generally High Current
- High Switching Speed
 - Low Capacitances / Cg
- No D-S parasitic Diode
- No Avalanche mode
- High Temperature
- High Cost

Characteristic	Unit	GaN	Si	SiC
Bandgap	eV	3.49	1.1	3.26
Electron mobility	cm²/Vs	2000	1500	700
Peak electron velocity	x10 ⁷ cm/s	2.1	1.0	2.0
Critical electric field	MV/cm	3.0	0.3	3.0
Thermal conductivity	W/cm * K	>1.5	1.5	4.5
Relative dielectric constant	er	9.0	11.8	10.0



Ref. Transphorm Technology

Performance Comparison

Si – GaAs - GaN

Advantageous in power supply circuits

High operating temperature Due to large bandgap and high potential barrier



Ref. GaN Systems website

Cascode Structure

Simple Depletion mode GaN FET with low Voltage series control Si MOSFET.

- Gate <u>is</u> a Si MOSFET
 - Small, low charge control FET
 - Rugged Si Gate structure
 - Complex dual-die structure
 - Higher packaging cost



Ref. Transphorm

Enhancement mode Structure

Panasonic



Panasonic makes normally-off by using P type GaN on the gate and discharge in the channel under the gate.

Normally-off can be made to reduce the number of electrons in the transistor and modified the gate structure.

Ref. Panasonic website

Example: PFC with GaN



Fig.1 Totem-pole bridgeless PFC boost converter based on GaN HEMT (a) Diode for line rectification (b) MOSFET for line rectification



Ref. Transphorm App. Note

GaN for 12 V PoL





Increasing Frequency → Small!

New Technology → Further reduction over time



The performance of eGaN FETs is expected to double every two years resulting in increased performance from a smaller form factor



V_{IN}=12 V V_{OUT}=1.2 V L=100 nH

Passive components, materials

Higher switching frequencies

- Lower loss magnetic core materials
- Innovative core geometries
- Low inductance packaging
 - Semiconductors
 - Capacitors
- Improved ripple current capacitors
- Higher frequency PWM controllers
 - Reduced delay times

Supplier links

GaN Systems: <u>http://www.gansystems.com/why_gallium_nitride_new.php</u>

EPC: <u>http://epc-co.com/epc/Applications/DC-DCConversion/PointofLoadConverters.aspx</u>

Transphorm: <u>http://www.transphormusa.com/applications/#power-supply</u>

Panasonic: <u>http://www.semicon.panasonic.co.jp/en/products/powerics/ganpower/#chap5</u>

CISCO TOMORROW starts here.